

## **Photonic Crystal Superlattices**

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- Field profiles
- Dispersion contours
- Refraction using *k*-vector analysis
- Conclusions











- Alternating rows posses different property ( $\Delta r$ ,  $\Delta n$ , or both)
- New unit cell definition with two holes per lattice point
- New BZ representation: hexagonal becomes rectangular
- BZ folding
- Symmetry reduction



n



- Increasing superlattice strength accomplished by increasing  $\Delta n$  or  $\Delta r$  between rows [i, j]
- Effective index: quantitative value of superlattice strength of static SL for comparison with dynamic SL
  - Take amount of material added to structure by reducing  $r_2$  hole and average the *n* over the area of  $r_1$  hole
- In Si, for  $r_2/r_1=0.857$ ,  $n_{eff}=1.654$  which is  $\Delta n=0.654$  between rows of holes



$$eff = \frac{n_b A_\delta + n_2 A_2}{A_1}$$
$$= n_b \left( 1 - \left(\frac{r_2}{r_1}\right)^2 \right) + n_2 \left(\frac{r_2}{r_1}\right)^2$$



## Effect of SL Strength on Band Structure ( $\Delta r$ )





- Decreasing r<sub>2</sub> increases amount of material in structure
- Stronger effect on air bands than dielectric bands
  - Shifts bands to lower frequencies
- Decreases width of PBG
- Increases band splitting
- Similar effect in dynamic superlattice when changing  $\Delta n$





- For no radius difference, BZ folding scheme is straight forward and curves converge to a single point at BZ boundaries.
- Increased SL strength causes curves to diverge/repel at BZ boundaries.
- Small SL strength: unmodified curvature in center of BZ with high curvature near BZ boundaries
- Large SL strength: modified curvature of entire contour.





## Band Structure: Bias Effects



Unbiased Biased  $r_2/r_1 = 0.571$ Isofrequency 0.5 line Normalized Frequency,  $\omega$ unbiased 0.3 biased 0.2 0.1 0 Y Χ Μ M k -vecto

PLZT (Scrymgeour *et al.*, APL **82**, 3176)

- PLZT background
- Bias of 6  $V/\mu m$
- Increase *n* from 2.49 to 2.598 (Δ*n*~ 0.11)
- Moves bands to lower frequencies
- Isofrequency line intersects bands at different points
- Dispersion surface
  'looks' different for
  unbiased/biased cases



- Isofrequency plane intersecting different areas of the dispersion surface
- The contours are congruent but shifted.
- Different contours results in different optical responses
  - Refraction/Beam steering
  - Switching/Modulation
  - Dispersion





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